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5 October 2015

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Dear Sirs

International Patent Application No PCT/GB2015/051478
Dielectric materials for low voltage OFET operation
The University of Manchester

In connection with the above patent application, we enclose a replacement declaration which has been signed and dated by the inventors, Michael L. TURNER, Sheida FARAJI and Leszek MAJEWSKI.

Yours faithfully

Nathan Hinks

Nathan Hinks
for and on behalf of HGF Limited
Agents for the Applicant

Aberdeen
Manchester

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